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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/718,897	11/20/2003		Shao-Chung Hu	JCLA11797	1661
23900	7590	04/05/2006		EXAMINER	
J C PATEN			ROSE, KIESHA L		
4 VENTURE, SUITE 250 IRVINE, CA 92618				ART UNIT	PAPER NUMBER
				2822	
				DATE MAILED: 04/05/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)
	10/718,897	HU ET AL.
Office Action Summary	Examiner	Art Unit
	Kiesha L. Rose	2822
The MAILING DATE of this communication app	pears on the cover sheet with the c	orrespondence address
Period for Reply A SHORTENED STATUTORY PERIOD FOR REPL' WHICHEVER IS LONGER, FROM THE MAILING D. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timwill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	l. lely filed the mailing date of this communication. (35 U.S.C. § 133).
Status		
Responsive to communication(s) filed on <u>24 Ja</u> This action is FINAL . 2b) ☐ This Since this application is in condition for allowed closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro	
Disposition of Claims		
4) ⊠ Claim(s) <u>15-23</u> is/are pending in the applicatio 4a) Of the above claim(s) is/are withdray 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>15-23</u> is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and/or	wn from consideration.	
Application Papers		U
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Example 11.	epted or b) objected to by the I drawing(s) be held in abeyance. See tion is required if the drawing(s) is objected.	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the attached detailed Office action for a list	s have been received. s have been received in Applicati rity documents have been receive u (PCT Rule 17.2(a)).	on No ed in this National Stage
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Do 5) Notice of Informal F 6) Other:	

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DETAILED ACTION

This Office Action is in response to the RCE filed 24 January 2006.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b); by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 15,16 and 21 are rejected under 35 U.S.C. 102(e) as being anticipated by Besser et al. (U.S. Patent 6,689,689).

In re claim 15, Besser discloses a damascene interconnect (Fig. 2) that contains a first dielectric layer (3), having a first opening (2) therein, a first metal layer (5), formed in the first opening and a first protective layer (7/8), formed on the surface of the first metal layer not covered by the first dielectric layer, wherein the first protective layer is formed from a mixture of the first metal layer and a first film layer (7/8), the first film layer is reactive with the first metal layer but non-reactive with the first dielectric layer and a top surface of the first dielectric layer around the first opening is exposed. (Column 7, lines 18-35 and Column 10, lines 41-67)

In re claim 16, the first metal layer is copper. (Column 9, lines 36-37)

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In re claim 21, the first film layer is comprised of a conductive material. (Column 7, lines 18-23)

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 17-20 and 22-23 are rejected under 35 U.S.C. 103(a) as being unpatentable over Besser as applied to claim 15 above, and further in view of Maiz et al. (U.S. Patent 6,794,755).

In re claim 17, Besser discloses all the limitations except for a first stop layer. Whereas Maiz discloses a interconnect structure (Fig. 2g) that contains a first stop layer (244) on the surface of the first dielectric layer (210) with the first opening formed in the first dielectric and the first stop layer. The first stop layer is formed to protect the copper interconnect during subsequent etch and cleaning procedures and to stop etchant and cleaning chemicals. (Column 6, lines 65-67 and Column 7, lines 1,2 and 7-9) Therefore it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the device of Besser by incorporating a first stop layer to protect the copper interconnect during subsequent etch and cleaning procedures and to stop etchant and cleaning chemicals as taught by Maiz.

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In re claim 18, Maiz discloses a second dielectric (246), formed over first dielectric (210), wherein the second dielectric layer has a second opening therein cutting through the first protective layer (216) to expose first metal layer (224), a second metal layer (280), being filled into the second opening, a second protective layer (interconnect structures can be formed of subsequent interconnect structures that would have the same layers as the first interconnect structure with the second protective layer. (Column 7, lines 53-55)), formed on the surface of the second metal layer not covered by the second dielectric. (Fig. 2g)

In re claim 19, Maiz discloses the second metal layer being copper. (Second metal layer is the same material as the first metal layer, Column 3, lines 28-30)

In re claim 20, Maiz discloses a second stop layer on the surface of the second dielectric layer, wherein the second opening is formed in the first dielectric and the second stop layer. (Addition interconnect structures can be formed of subsequent interconnect structures that would have the same layers as the first interconnect structures with a second stop layer. (Column 7, lines 53-55))

In re claims 22 and 23, Besser and Maiz disclose the second protective layer formed from a mixture of the second metal layer and a second film layer and the second film layer is reactive with the second metal layer but non-reactive with the second dielectric. Besser discloses a first film that is reactive with the first metal layer and non-reactive with the first dielectric and Besser discloses that subsequent layers can be formed, which would be another interconnect layer with second protective layer and second film layer (Column 11, lines 8-11) and where the second film layer would be

formed of a conductive material as the first film layer. (Column 7, lines 18-23) In addition Maiz discloses subsequent interconnect structures where the first and second protective layers can be formed on the first and second metal layers with first and second film layers. (Column 7, lines 53-55)

Response to Arguments

Applicant's arguments with respect to claims 15-23 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Kiesha L. Rose whose telephone number is 571-272-1844. The examiner can normally be reached on T-F 8:30-6:00 off Mondays.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Zandra Smith can be reached on 571-272-2429. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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